

General Description

Maxim's redesigned DG417/DG418/DG419 precision, CMOS, monolithic analog switches now feature guaranteed on-resistance matching (3 Ω max) between switches and guaranteed on-resistance flatness over the signal range (4 Ω max). These switches conduct equally well in either direction and guarantee low charge injection, low power consumption, and an ESD tolerance of 2000V minimum per Method 3015.7. The new design offers low off-leakage current over temperature (less than 5nA at +85°C).

The DG417/DG418 are single-pole/single-throw (SPST) switches. The DG417 is normally closed, and the DG418 is normally open. The DG419 is singlepole/double-throw (SPDT) with one normally closed switch and one normally open switch. Switching times are less than 175ns max for ton and less than 145ns max for toff. Operation is from a single +10V to +30V supply, or bipolar $\pm 4.5 \text{V}$ to $\pm 20 \text{V}$ supplies. The improved DG417/DG418/DG419 are fabricated with a 44V silicon-gate process.

Applications

Sample-and-Hold Circuits Communications Systems Test Equipment Battery-Operated Systems Modems Fax Machines Guidance and Control Systems PBX, PABX Audio Signal Routing Military Radios

New Features

- Plug-In Upgrades for Industry-Standard DG417/DG418/DG419
- **♦ Improved Rps(ON) Match Between Channels** $(3\dot{\Omega} \text{ max}, DG4\dot{1}9 \text{ only})$
- Guaranteed RFLAT(ON) Over Signal Range (4Ω max)
- ♦ Improved Charge Injection (10pC max)
- **♦ Improved Off-Leakage Current Over Temperature** (<5nA at +85°C)
- **♦ Withstand Electrostatic Discharge (2000V min)** per Method 3015.7

Existing Features

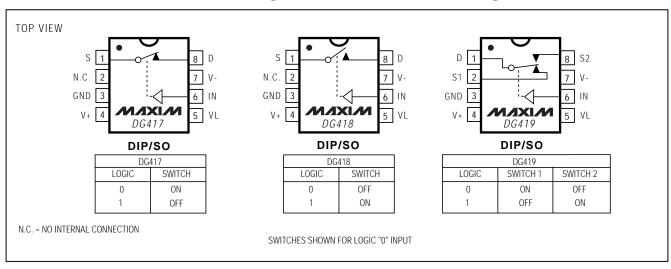
- Low R_{DS(ON)} (35Ω max)
- Single-Supply Operation +10V to +30V Bipolar-Supply Operation ±4.5V to ±20V
- ♦ Low Power Consumption (35µW max)
- ♦ Rail-to-Rail Signal Handling
- ♦ TTL/CMOS-Logic Compatible

Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
DG417CJ	0°C to +70°C	8 Plastic DIP
DG417CY	0°C to +70°C	8 SO
DG417C/D	0°C to +70°C	Dice*
DG417DJ	-40°C to +85°C	8 Plastic DIP
DG417DY	-40°C to +85°C	8 SO

Ordering Information continued at end of data sheet.

Pin Configurations/Functional Diagrams/Truth Tables



^{*} Contact factory for dice specifications.

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to V-	
V+	44V
GND	25V
VL(C	SND - $0.3V$) to $(V + + 0.3V)$
Digital Inputs Vs, VD (Note 1)(V-	- 2V) to (V+ + 2V) or 30mA
Continuous Current (any terminal) (No	te 1)30mA
Peak Current, S or D (pulsed at 1ms, 10	% duty cycle max)100mA

Continuous Power Dissipation ($T_A = +70$ °C)	
Plastic DIP (derate 9.09mW/°C above +70°	C)727mW
SO (derate 5.88mW/°C above +70°C)	471mW
CERDIP (derate 8.00mW/°C above +70°C)	640mW
Operating Temperature Ranges	
DG41_C	0°C to +70°C
DG41_D	40°C to +85°C
DG41_AK	55°C to +125°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10sec)	+300°C

Note 1: Signals on S, D, or IN exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

 $(V+=+15V, V-=-15V, VL=5V, GND=0V, V_{INL}=0.8V, V_{INH}=2.4V, T_A=T_{MIN}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL		MIN	TYP (Note 2)	MAX	UNITS					
SWITCH	1	ı									
Analog Signal Range	V _{S_} , V _D	(Note 3)				-15		15	V		
Drain-Source		V+ = 13.5V, V- = -13.5V, V _D = ±10V,		$T_A = +25^{\circ}C$	C, D		20	35			
On-Resistance	R _{DS} (ON)			TA = 123 C	А		20	30	Ω		
- Trociotarios		Is = -10mA		$T_A = T_{MIN}$ to T	MAX			45			
On-Resistance Match Between Channels	ΔR _{DS} (ON)	V+ = 15V, V- = VD = ±10V,	V+ = 15V, V- = -15V,					3	Ω		
(Note 4)	71(D2(ON)	$I_S = \pm 10V$, $I_S = -10\text{mA}$		TA = TMIN to T	MAX			4			
On-Resistance Flatness		V+ = 15V, V- = -15V,		TA = +25°C				4	Ω		
(Note 4)	RFLAT(ON)	$V_D = \pm 5V$, $I_S = -10$ mA		TA = TMIN to TMAX			6				
Source-Off	I _{S(OFF)}	V+ = 16.5V, V- = -16.5V		$T_A = +25^{\circ}C$		-0.25		0.25			
Leakage Current		$V_D = \pm 15.5 V$,		177 1101114 10	C, D	-5		5	nA		
(Note 5)		$V_S = \mp 15.5V$		Тмах	А	-20		20			
	I _{D(OFF)}		DG417/ DG418 DG419	T _A = +25°C		-0.25	0.1	0.25	nA		
D ! 0"		V+ = 16.5V, V- = -16.5V,		$T_A = T_{MIN}$ to T_{MAX}	C, D	-5		5			
Drain-Off Leakage Current					А	-20		20			
(Note 5)	I ID(OFF)	$V_D = \pm 15.5V,$ $V_S = \mp 15.5V$		T _A = +25°C		-0.75	-0.1	0.75			
		VS = +15.5V		$T_A = T_{MIN}$ to	C, D	-10		10			
				T _{MAX}	А	-40		40			
Drain-On Leakage Current (Note 5)			DG417/ DG418	$T_A = +25^{\circ}C$		-0.4		0.4			
	I _{D(ON)}	$V+ = 16.5V, \\ V- = -16.5V, \\ V_D = \pm 15.5V, \\ V_S = \pm 15.5V$		TA = TMIN to	C, D	-10		10	nA		
				TMAX	А	-40		40			
			DG419	$T_A = +25^{\circ}C$		-0.75		0.75			
				TA = TMIN to	C, D	-10		10			
				T _{MAX}	Α	-40		40			

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

 $(V + = +15V, V - = -15V, VL = 5V, GND = 0V, V_{INL} = 0.8V, V_{INH} = 2.4V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP (Note 2)	MAX	UNITS	
LOGIC INPUT				l					
Logic Input Current with Input Voltage High	linh	V _{IN} = 2.4V	V _{IN} = 2.4V			0.005	0.5	μΑ	
Logic Input Current with Input Voltage Low	linl	V _{IN} = 0.8V	V _{IN} = 0.8V			0.005	0.5	μΑ	
DYNAMIC									
Turn-On Time	ton	DG417/DG418, V _D = ±10V, Figure 2		$T_A = +25^{\circ}C$ $T_A = T_{MIN} \text{ to } T_{MAX}$		100	175 250	ns	
Turn-Off Time	toff	DG417/DG418, V _D = ±10V, Figure 2		$T_A = +25^{\circ}C$ $T_A = T_{MIN} \text{ to } T_{MAX}$		60	145 210	ns	
Transition Time	t _{TRANS}	DG419, $V_S = \pm 10V$, Figure 3		$T_A = +25^{\circ}C$ $T_A = T_{MIN} \text{ to } T_{MAX}$			175 250	ns	
Break-Before-Make Interval	t _D	DG419, V _{S1} = V _{S2} = ±	DG419, $V_{S1} = V_{S2} = \pm 10V$, Figure 4, $T_A = +25$ °C		5	13		ns	
Charge Injection (Note 3)	Q	VGEN = 0V, Figure 5, T _A = +25°C				3	10	рС	
Off-Isolation Rejection Ratio (Note 6)	OIRR	$R_L = 500\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 6, $T_A = +25^{\circ}C$				68		dB	
Crosstalk (Note 7)		DG419, R _L = 50Ω , C _L = $5pF$, f = $1MHz$, Figure 7, T _A = $+25$ °C				85		dB	
Drain Off-Capacitance	C _D (OFF)	$V_D = 0V$, $f = 1MHz$, Figure 8, $T_A = +25$ °C			8		рF		
Source Off-Capacitance	C _S (OFF)	V _D = 0V, f = 1MHz, Figure 8, T _A = +25°C			8		рF		
Drain-Source On-Capacitance	C _D (ON)	V _S = 0V, f = 1MHz, DG417/DG418 Figure 9,			30		pF		
Cs (ON) TA		T _A = +25°C DG419		19	35				
SUPPLY									
Positive Supply Current	nt I+	V+ = 16.5V, V- = -16.5V, V _{IN} = 0V or 5V		$T_A = +25^{\circ}C$	-1	-0.0001	1	- μΑ	
1 ositive Supply Current				$T_A = T_{MIN}$ to T_{MAX}	-5		5		
Negative Supply Current	-	V+ = 16.5V, V- = -16.5V,		T _A = +25°C	-1	-0.0001	1	μΑ	
gative supply surrent		V _{IN} = 0V or 5V		TA = TMIN to TMAX	-5		5	μ,,	
Logic Supply Current	IL	V+ = 16.5V, V- = -16.5V, V _{IN} = 0V or 5V		$T_A = +25^{\circ}C$	-1	-0.0001	1	μА	
J				TA = TMIN to TMAX	-5		5		
Ground Current	I IONID I		V- = -16.5V, TA = +25°C		-1	-0.0001	1	μΑ	
	SIND	$V_{IN} = 0V \text{ or } 5V$ $T_A = T_{MIN} \text{ to } T_{MAX}$		-5		5			

ELECTRICAL CHARACTERISTICS—Single Supply

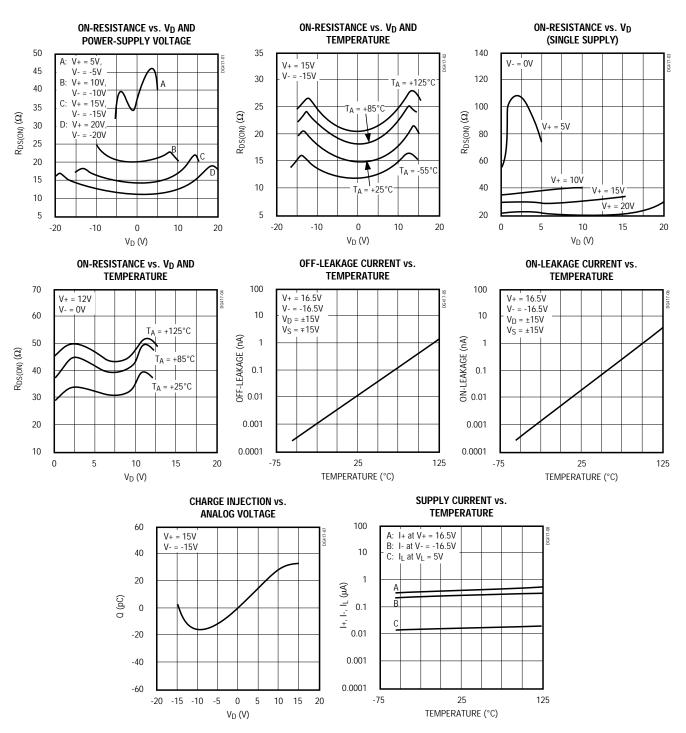
 $(V + = +12V, V - = 0V, VL = 5V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = +25^{\circ}C$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP (Note 2)	MAX	UNITS
SWITCH	l					
Analog Signal Range	Vanalog	(Note 3)	0		12	V
Drain-Source On-Resistance	R _{DS} (ON)	$I_S = -10 \text{mA}, V_D = 3.8 \text{V}, V_{+} = 10.8 \text{V}$		40	100	Ω
DYNAMIC						•
Turn-On Time	t _{ON}	DG417/DG418, V _D = 8V, Figure 2		110		ns
Turn-Off Time	toff	DG417/DG418, V _D = 8V, Figure 2		40		ns
Break-Before-Make Interval	t _D	DG419, $R_L = 1000\Omega$, $C_L = 35pF$, Figure 4		60		ns
Charge Injection (Note 3)	Q	C _L = 10nF, V _{GEN} = 0V, R _{GEN} = 0V, Figure 5		2	10	рС
SUPPLY						•
Positive Supply Current	I+	All channels on or off, $V+=13.2V$, $V_L=5.25V$, $V_{IN}=0V$ or $5V$		-0.0001		μА
Negative Supply Current	I-	All channels on or off, $V_{+} = 13.2V$, $V_{L} = 5.25V$, $V_{IN} = 0V$ or $5V$	-0.0001		μА	
Logic Supply Current	ΙL	All channels on or off, $V_L = 5.25V$, $V_{IN} = 0V$ or $5V$	-0.0001		μА	
Ground Current	I _{GND}	All channels on or off, $V_L = 5.25V$, $V_{IN} = 0V$ or $5V$ -0.0001			μА	

- **Note 2:** Typical values are for **design aid only**, are not guaranteed, and are not subject to production testing. The algebraic convention where the most negative value is a minimum and the most positive value a maximum is used in this data sheet.
- Note 3: Guaranteed by design.
- **Note 4:** On-resistance match between channels and flatness is guaranteed only with bipolar-supply operation. Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured at the extremes of the specified analog range.
- Note 5: Leakage parameters I_{S(OFF)}, I_{D(OFF)}, and I_{D(ON)} are 100% tested at the maximum rated hot temperature and guaranteed by correlation at +25°C.
- Note 6: Off-Isolation Rejection Ratio = 20log (V_D/V_S), V_D = output, V_S = input to off switch.
- Note 7: Between any two switches.

Typical Operating Characteristics

 $(T_A = +25$ °C, unless otherwise noted.)



Pin Description

	PIN		NAME	FUNCTION	
DG417	DG418	DG419	INAIVIE	FUNCTION	
1	_	_	S	Analog-Switch Source Terminal (normally closed)	
_	1	_	S	Analog-Switch Source Terminal (normally open)	
_	_	2	S1	Analog-Switch Source Terminal 1 (normally closed)	
2	2	_	N.C.	No Internal Connection	
3	3	3	GND	Logic Ground	
4	4	4	V+	Analog-Signal Positive Supply Input	
5	5	5	VL	Logic-Level Positive Supply Input	
6	6	6	IN	Logic-Level Input	
7	7	7	V-	Analog-Signal Negative Supply Input	
8	8	1	D	Analog-Switch Drain Terminal	
_	_	8	S2	Analog-Switch Source Terminal 2 (normally open)	

_Applications Information

Operation with Supply Voltages Other than ±15V

Using supply voltages other than $\pm 15V$ reduces the analog signal range. The DG417/DG418/DG419 switches operate with $\pm 4.5V$ to $\pm 20V$ bipolar supplies or with a $\pm 10V$ to $\pm 30V$ single supply; connect V- to 0V when operating with a single supply. Also, all device types can operate with unbalanced supplies, such as $\pm 24V$ and $\pm 5V$. VL must be connected to $\pm 5V$ to be TTL compatible, or to V+ for CMOS-logic level inputs. The Typical Operating Characteristics graphs show typical on-resistance with $\pm 20V$, $\pm 15V$, $\pm 10V$, and $\pm 5V$ supplies. (Switching times increase by a factor of two or more for operation at $\pm 5V$.)

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, followed by VL, V-, and logic inputs. If power-supply sequencing is not possible, add two small, external signal diodes in series with the supply pins for overvoltage protection (Figure 1).

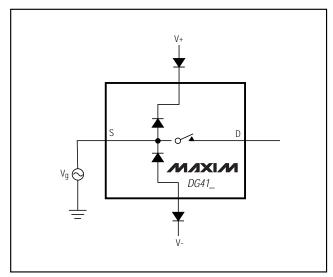


Figure 1. Overvoltage Protection Using External Blocking Diodes

Adding diodes reduces the analog signal range to 1V below V+ and 1V above V-, without affecting low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed +44V.

Test Circuits/Timing Diagrams

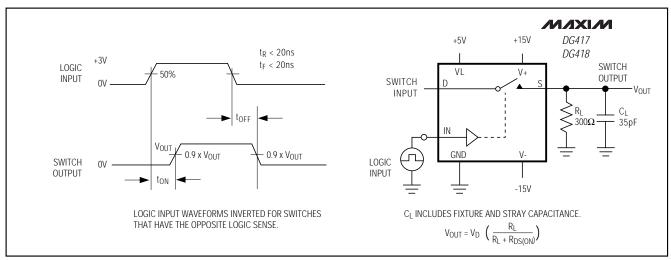


Figure 2. DG417/DG418 Switching Time

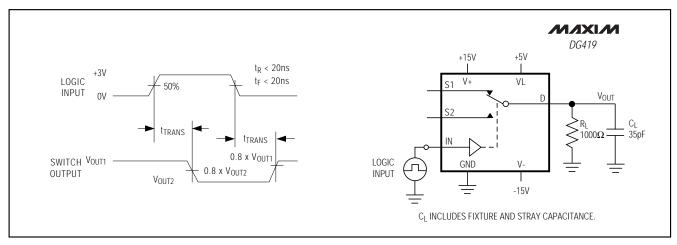


Figure 3. DG419 Transition Time

Test Circuits/Timing Diagrams (continued)

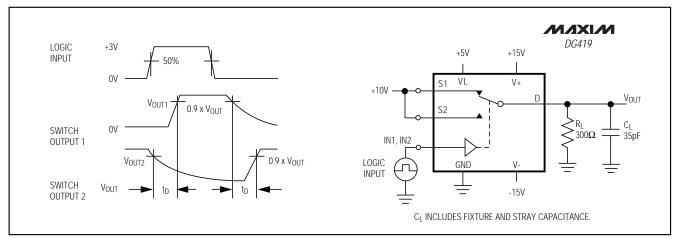


Figure 4. DG419 Break-Before-Make Interval

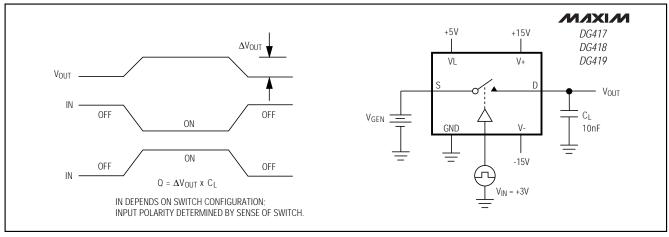


Figure 5. Charge Injection

Test Circuits/Timing Diagrams (continued)

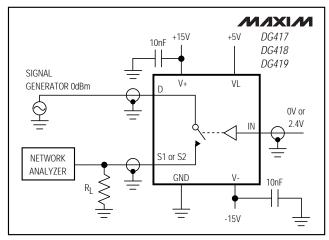


Figure 6. Off-Isolation Rejection Ratio

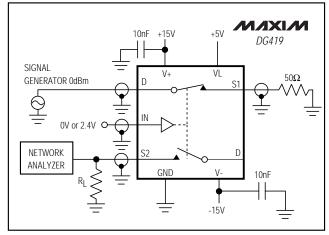


Figure 7. DG419 Crosstalk

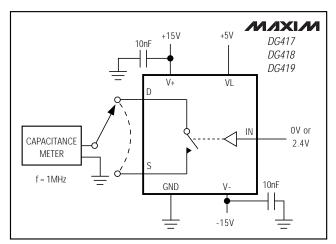


Figure 8. Drain-Source Off-Capacitance

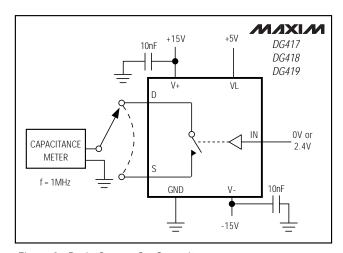


Figure 9. Drain-Source On-Capacitance